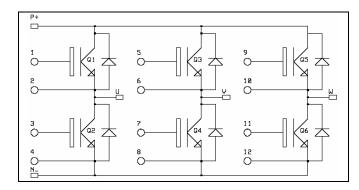
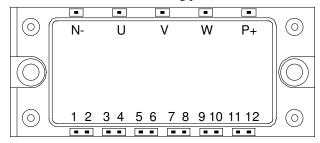
# APTGF50X60E2 APTGF50X60P2

# 3 Phase bridge NPT IGBT Power Module

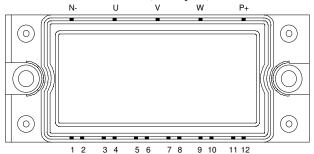
$$\begin{split} V_{CES} &= 600V \\ I_C &= 50A @ Tc = 80^{\circ}C \end{split}$$



## Pin out: APTGF50X60E2 (Long pins)



#### Pin out: APTGF50X60P2 (Short pins)



### **Application**

• AC Motor control

#### **Features**

- Non Punch Through (NPT) Fast IGBT®
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 50 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - Avalanche energy rated
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile

# All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

#### **Absolute maximum ratings**

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		600	V
$I_{\rm C}$	Continuous Collector Current	$T_C = 25^{\circ}C$	70	
	Continuous Conector Current	$T_C = 80^{\circ}C$	50	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	125	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_D$	Maximum Power Dissipation	$T_C = 25^{\circ}C$	250	W
SCSOA	Short Circuit Safe Operating Area	$T_j = 125^{\circ}C$	225A@360V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.

# APTGF50X60E2 APTGF50X60P2

## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$BV_{CES}$	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 500 \mu A$		600			V
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$		1	500	μΑ
		$V_{CE} = 600V$ $T_j = 125$	$T_j = 125$ °C		1		mA
V <sub>CE(on)</sub>	Collector Emitter on Voltage		$T_j = 25^{\circ}C$		1.95	2.45	V
				2.2		V	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		3		6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

·	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$		2200		pF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz		200		pr
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		40		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		9		
$T_{d(off)} \\$	Turn-off Delay Time	$I_C = 50A$		120		
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.7\Omega$		12		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		42		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 50A$		10		ns
$T_{d(off)}$	Turn-off Delay Time			130		115
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.7\Omega$		21		
$E_{\text{off}}$	Turn off Energy			1.0		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{F}$	Diode Forward Voltage	$I_F = 50A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.25	1.6	V
		$V_{GE} = 0V$	$T_i = 125$ °C		1.2		ľ
$E_R$	Reverse Recovery Energy	$I_F = 50A$ $V_R = 300V$ $di/dt = 800A/\mu s$	$T_j = 125$ °C		1.5		mJ
$Q_{rr}$	Reverse Recovery Charge	$I_F = 50A$	$T_j = 25^{\circ}C$		3.4		
		$V_R = 300V$ di/dt =800A/µs	$T_j = 125$ °C		5.6		μC

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
$R_{thJC}$	Junction to Case		IGBT			0.5	°C/W
	Junction to Case		Diode			0.8	C/ VV
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case			2500			V
* ISOL	I isol<1mA, 50/60Hz			2300			<b>,</b>
$T_{J}$	Operating junction temperature range		-40		150		
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature					125	
Torque	Mounting torque	To Heatsink	M5	2		3.5	N.m
Wt	Package Weight					185	g

### Package outline

Pin out: APTGF50X60E2 (Long pins) 0,8- $\overline{+}$ ±0,3≠ 6,9 Ø 5,5 20,95\* 20,95\*  $17 \pm 0,5$ 0 16,02\* 19,83\* 16,02\* 27,45\* 31,26\* 31,26\* 38,88\* 42,69\* ±0,3-CONVEX 46,5\* 93 50,31\* **7**0,25 54,12\* 61,74\* 65,55\* 61,74\* - 73,17\* - 76,98\* 76,98\* 14+0,8 **∢**11→  $\emptyset$  2,1-6 (4x) 32 ±0,3 Ø 6 (4x)

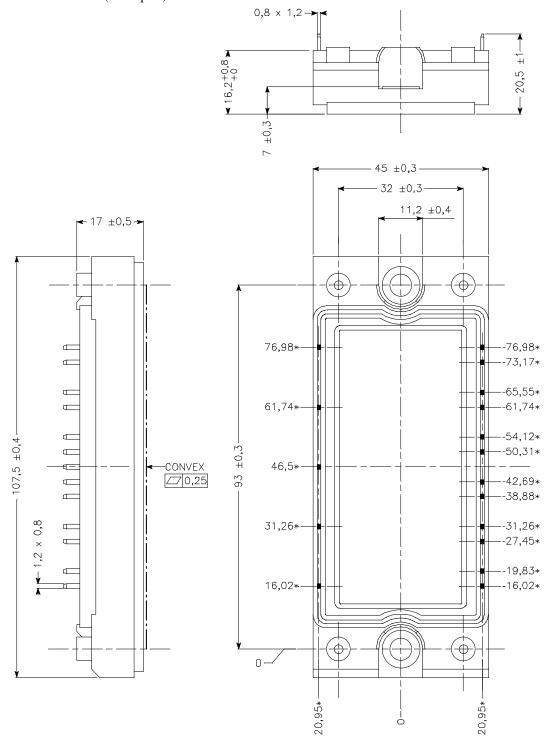
ALL DIMENSIONS MARKED "\*" ARE TOLERENCED AS:

45 ±0,3

# APTGF50X60E2 APTGF50X60P2

## Package outline

Pin out: APTGF50X60P2 (Short pins)



#### APT reserves the right to change, without notice, the specifications and information contained herein

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